DESIGN EXAMPLE REPORT

Title	***3.25 W CV/CC Charger Using LNK632DG***
Specification	85 – 265 VAC Input; 5 V, 0.5 A (Name Plate) Output
Application	Low Cost Charger or Adapter
Author	Applications Engineering Department
Document Number	DER-207
Date	February 25, 2009
Revision	1.0

Summary and Features

- Revolutionary control concept provides very low cost, low part-count solution
    - Primary-side control eliminates secondary-side control and optocoupler
    - 700 V MOSFET rating allows Clampless™ design - eliminates primary clamp components
    - Provides ±5% constant voltage (CV) and ±18% constant current (CC) accuracy including output cable voltage drop compensation for 26 AWG (0.4 Ω) or 28 AWG (0.75 Ω) cables
    - Over-temperature protection – tight tolerance (±5%) with hysteretic recovery for safe PCB temperatures under all conditions
    - Auto-restart output short circuit and open-loop protection
- EcoSmart® – Easily meets all current international energy efficiency standards – China (CECP) / CEC / ENERGY STAR 2 / EU CoC
    - No-load input energy consumption: <30 mW at 265 VAC
    - Ultra-low leakage current: <5 µA at 265 VAC input (no Y capacitor required)
- Design easily meets EN550022 and CISPR-22 Class B EMI with >10 dB margin
- Meets IEC 61000-4-5 Class 3 AC line surge
- Meets IEC 61000-4-2 ESD immunity (contact and air discharge at 15 kV)
- Meets <5 µA battery discharge requirement

Power Integrations
5245 Hellyer Avenue, San Jose, CA 95138 USA.
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

Table of Contents

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

Important Note:
Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.

1 Introduction

This engineering report describes a 2.50 W constant voltage/constant current (CV/CC) universal input charger power supply for a cell phone. The power supply utilizes the LinkSwitch-II product LNK632DG.

The LinkSwitch-II was developed to cost effectively replace all existing solutions in low-power charger and adapter applications. Its controller is optimized for CV/CC charging applications, for minimal external part count, and for very tight control of the output voltage and moderate current regulation without the use of an optocoupler. The integrated 700 V switching MOSFET and ON/OFF control function achieve both high efficiency under all load conditions, and low no-load energy consumption. No-load performance and operating efficiency exceed all current and proposed international energy efficiency standards.

A unique ON/OFF control scheme provides voltage regulation, as well as support for cable voltage-drop compensation, and tight regulation over a wide temperature range. The output current is regulated by modulating the switching frequency to provide moderately tight CC characteristic.

The LNK632DG controller consists of an oscillator, feedback (sense and logic) circuitry, a 5.8 V regulator, BYPASS (BP) pin programming functions, over-temperature protection, frequency jittering, current-limit circuitry, leading-edge blanking, a frequency controller for CC regulation, and an ON/OFF state machine for CV control.

The LNK632DG also provides a sophisticated range of protection features including auto-restart for control loop component open/short circuit faults and output short-circuit conditions. Accurate hysteretic thermal shutdown ensures safe average PCB temperatures under all conditions.

The IC package provides extended creepage distance between high and low voltage pins (both at the package and the PCB), which is required in very humid conditions to prevent arcing and to further improve reliability.

The LNK632DG can be configured as either self-biased from the high voltage drain pin or supplied via an optional bias supply. When configured as self biased, the very low IC current consumption provides a worst-case no-load power consumption of approximately 200 mW at 265 VAC, well within the 300 mW European Union CoC requirement. When fed from an optional bias supply (as in this design), the no-load power consumption reduces to <30 mW.

The EE16 transformer bobbin in this design provides extended creepage to meet safety spacing requirements. Both the EF12.6 and EE13 core sizes could also have been used at this power level.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

This document contains the power supply specifications, schematic, bill of materials, transformer specifications, and typical performance characteristics for this reference design using the LNK632DG.

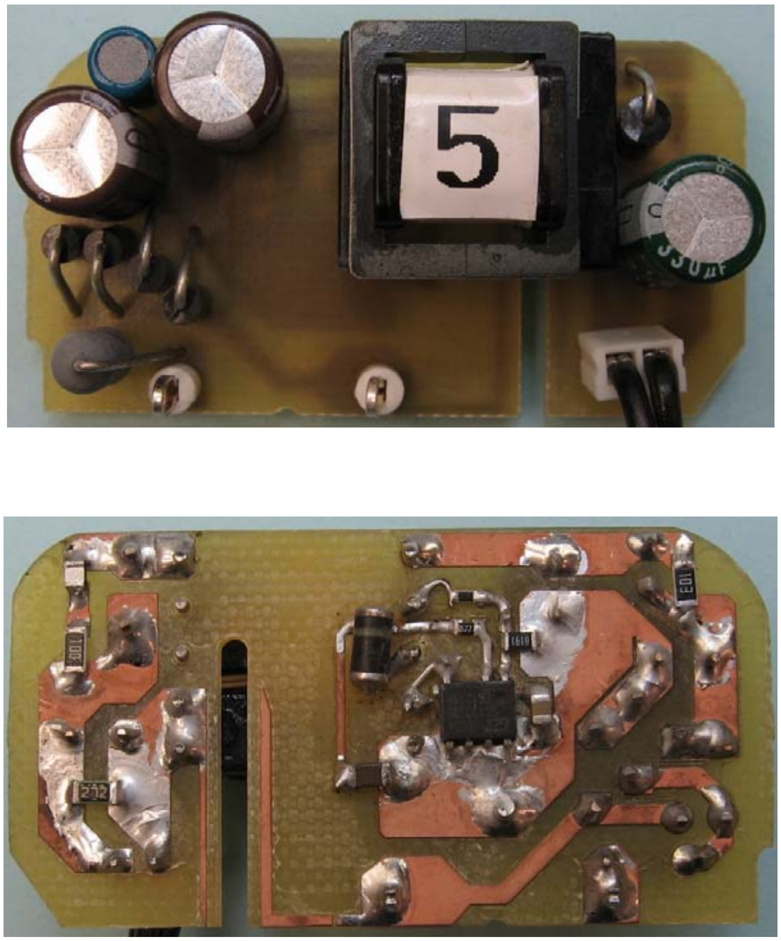


Figure 1 – Populated Circuit Board Photograph.

2 Power Supply Specification

Description	Symbol	Min	Typ	Max	Units	Comment
Input						
Voltage	V_{IN}	85		265	VAC	2 Wire – no P.E.
Frequency	f_{LINE}	47	50/60	64	Hz	
No-load Input Power (230 VAC)				0.03	W	
Output						
Output Voltage	V_{OUT}	4.75	5.0	5.25	V	± 5%
Output Ripple Voltage	V_{RIPPLE}		100	200	mV	20 MHz bandwidth
Output Current	I_{OUT}	0.5	0.65	0.8	A	
Output Power	P_{OUT}		3.25		W	
Output Cable Resistance	R_{CBL}		0.6		Ω	28 AWG, 6 ft
Name plate output rating						
Nameplate Voltage	V_{NP}		5		V	
Nameplate Current	I_{NP}		0.5		A	
Nameplate Power	P_{NP}		2.5		W	
Efficiency						
Full Load	η	70			%	Measured at P_{OUT} 25 °C
Required average efficiency per EU Code of Conduct V3	$\eta_{EU(CoC)}$	62	Measured Measured per Energy Star "Test Method for Calculating the Energy Efficiency of Single-Voltage External AC-DC and AC-AC Power Supplies (August 11, 2004)".			
Required average efficiency per ENERGY STAR V2	$\eta_{ES2.0}$	63	$\eta_{EU(CoC)}$: (0.095 ln(P_{NP})+0.529 η_{ESV2}: (0.075 ln(P_{NP})+0.561			
Environmental						
Conducted EMI	Meets CISPR22B / EN55022B					> 6 dB margin
Safety	Designed to meet IEC950 / UL1950 Class II					
Surge		1 2			kV	1.2/50 µs surge, IEC 1000-4-5, Series Impedance: Differential Mode: 2 Ω Common Mode: 12 Ω
ESD		-15		15	kV	Contact and air discharge onto output connector
Ambient Temperature	T_{AMB}	0		40	°C	Free convection, sea level. Assembly is installed in a standard plastic enclosure.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

3 Schematic

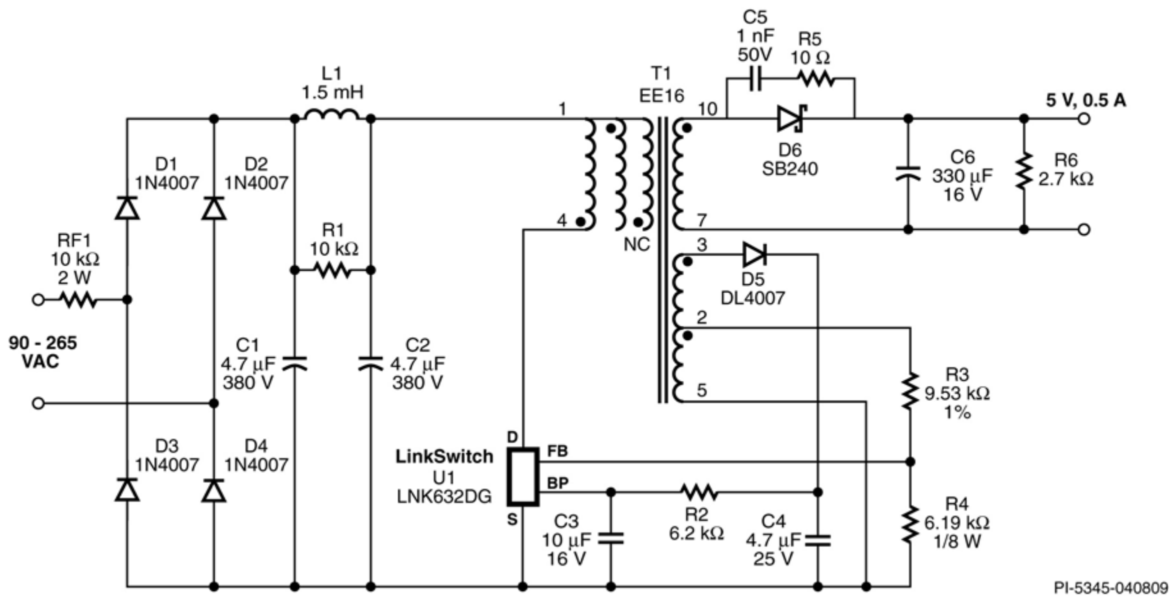


Figure 2 – Schematic.

4 Circuit Description

This circuit uses the LNK632DG in a primary-side regulated flyback power supply configuration.

4.1 Input Filter

The AC input power is rectified by diodes D1 through D4. Bulk storage capacitors C1 and C2 filter the rectified AC. Inductor L1 forms a pi (π) filter with C1 and C2 to attenuate conducted differential-mode EMI noise. This configuration, and the use of Power Integrations' transformer E-Shield® technology, allows this supply to comply with EMI standard EN55022 class B, with good margin, and without a Y capacitor. Fusible resistor RF1 provides protection against catastrophic failure. It should be rated to withstand the instantaneous dissipation when the supply is first connected to AC input (while the input capacitors charge) at VAC_{MAX}. This means choosing either an over-sized metal-film or a wire-wound resistor. This design uses a wire-wound resistor for RF1.

4.2 LNK632DG Primary

The LNK632DG device (U1) incorporates the power switching device, an oscillator, a CC/CV control engine, startup circuitry, and protection functions into one IC. The integrated 700 V MOSFET allows sufficient voltage margin for universal input AC applications. The device is completely self-powered from the BYPASS pin (BP) and decoupling capacitor C3. Capacitor C3 also selects the output voltage cable-drop compensation amount. For this design enhanced cable voltage drop compensation was selected by choosing a 10 μF value (to compensate the drop of a 0.6 Ω, 28 AWG output cable). The optional bias circuit consisting of D5, C4, and R2 increases efficiency and reduces the no-load input power to less than 30 mW at 265 VAC.

The rectified and filtered input voltage is applied to one side of transformer T1's primary winding. The integrated MOSFET in U1 drives the other side of T1's primary winding. This design does not require a primary side clamp circuit.

4.3 Output Rectification and Filtering

Transformer T1's secondary is rectified by D6 and filtered by C6. A Schottky barrier-type diode was selected for higher efficiency. Capacitor C7 was selected to have a sufficiently low ESR to meet the output voltage ripple requirement without using an LC post-filter. If it provides lower cost overall, select a smaller value for C7, and follow it with a ferrite bead and another capacitor (100 μF) to provide the necessary filtering to meet the output ripple specification

In designs where lower (3% to 4%) average efficiency is acceptable, diode D6 may be replaced by a PN-junction diode to lower cost. Note that R3 and R4 must be re-adjusted to ensure the output voltage stays centered.

Capacitor C5 and R5 form a snubber network to both limit the magnitude of the transient voltage spikes that appear across D6 and reduce radiated EMI.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

Resistor R6 form the output pre-load, necessary to prevent the output voltage rising at no-load.

4.4 Output Regulation

The LNK632DG eliminates the optocoupler by using a primary side AC winding sense on T1. The LNK632DG regulates by using ON/OFF control for CV regulation and frequency control for CC regulation. The feedback resistors (R3 and R4) were selected using standard 1% resistor values to center both the nominal output voltage and constant current regulation thresholds.

5 PCB Layout

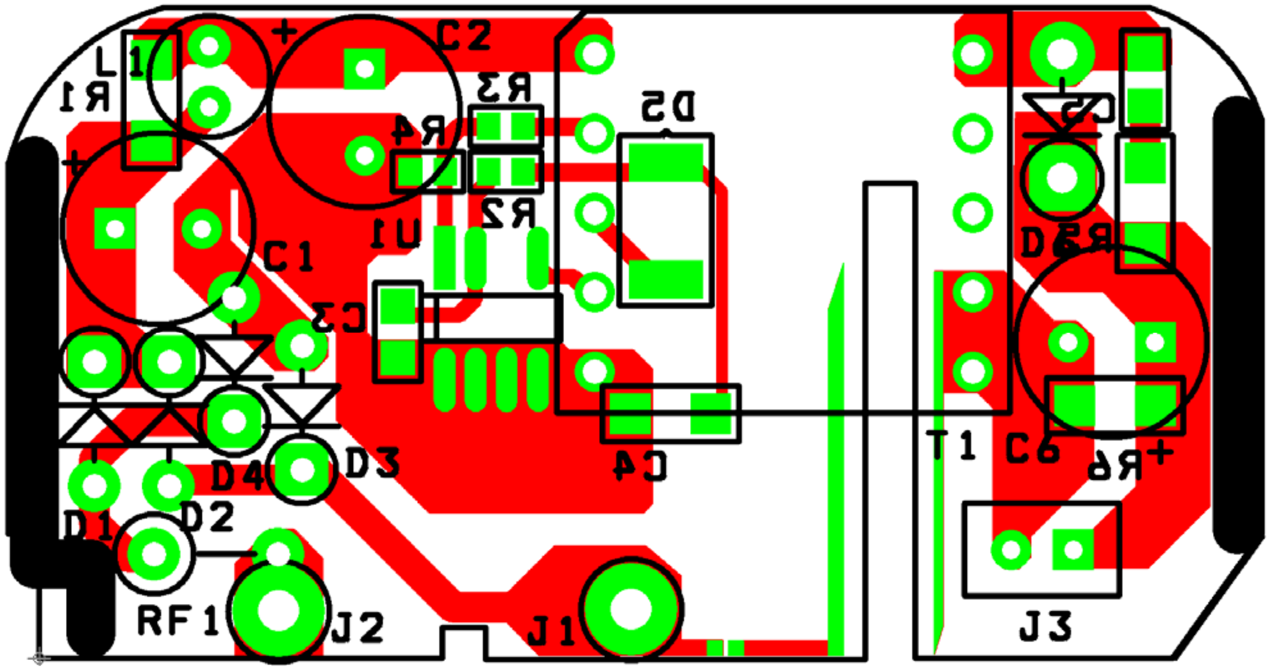


Figure 3 – Printed Circuit Layout.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

6 Bill of Materials

Item	Qty	Ref Des	Description	Mfg	Mfg Part Number
1	2	C1 C2	4.7 μF, 380 V, Electrolytic, (8 x 11.5)	Nippon Chemi-Con	XX380VB4R7M8X11LL
2	1	C3	10 μF, 16 V, Ceramic, X5R, 0805	Murata	GRM21BR61C106KE15L
3	1	C4	4.7 μF, 25 V, Ceramic, X7R, 1206	Panasonic	ECJ-3YB1E475M
4	1	C5	1 nF, 50 V, Ceramic, X7R, 0805	Panasonic	ECJ-2VB1H102K
5	1	C6	330 μF, 16 V, Electrolytic, Very Low ESR, 72 m Ω, (8 x 11.5)	Nippon Chemi-Con	EKZE160ELL331MHB5D
6	4	D1 D2 D3 D4	1000 V, 1 A, Rectifier, DO-41	Vishay	1N4007-E3/54
7	1	D5	1000 V, 1 A, Rectifier, Glass Passivated, DO-213AA (MELF)	Diodes Inc	DL4007-13-F
8	1	D6	40 V, 2 A, Schottky, DO-204AC	Vishay	SB240
9	2	J1 J2	Test Point, WHT,THRU-HOLE MOUNT	Keystone	5012
10	1	J3	6 ft, 26 AWG, 2.1 mm connector (custom)	Anam Instruments (Korea)	3PH323A0
11	1	L1	1.5 mH, 0.18 A, 5.5 x 10.5 mm	Tokin	SBC1-152-181
12	1	R1	10 kΩ, 5%, 1/4 W, Metal Film, 1206	Panasonic	ERJ-8GEYJ103V
13	1	R2	6.2 kΩ, 5%, 1/10 W, Metal Film, 0603	Panasonic	ERJ-3GEYJ622V
14	1	R3	9.53 kΩ, 1%, 1/16 W, Metal Film, 0603	Panasonic	ERJ-3EKF9531V
15	1	R4	6.19 kΩ, 1%, 1/16 W, Metal Film, 0603	Panasonic	ERJ-3EKF6191V
16	1	R5	10 Ω, 5%, 1/4 W, Metal Film, 1206	Panasonic	ERJ-8GEYJ100V
17	1	R6	2.7 kΩ, 5%, 1/4 W, Metal Film, 1206	Panasonic	ERJ-8GEYJ272V
18	1	RF1	10 Ω, 2 W, Fusible/Flame Proof Wire Wound	Vitrohm	CRF253-4 10R
19	1	T1	Custom transformer per Power Integrations transformer drawing. Bobbin, EE16 Extended Creepage, Horizontal, 10 pins	Taiwan Shulin Enterprise Co. LTD	TF-1613
20	1	U1	LinkSwitch-II, LNK632DG, CV/CC, SO-8-C	Power Integrations	LNK632DG

7 Transformer Specification

7.1 Electrical Diagram

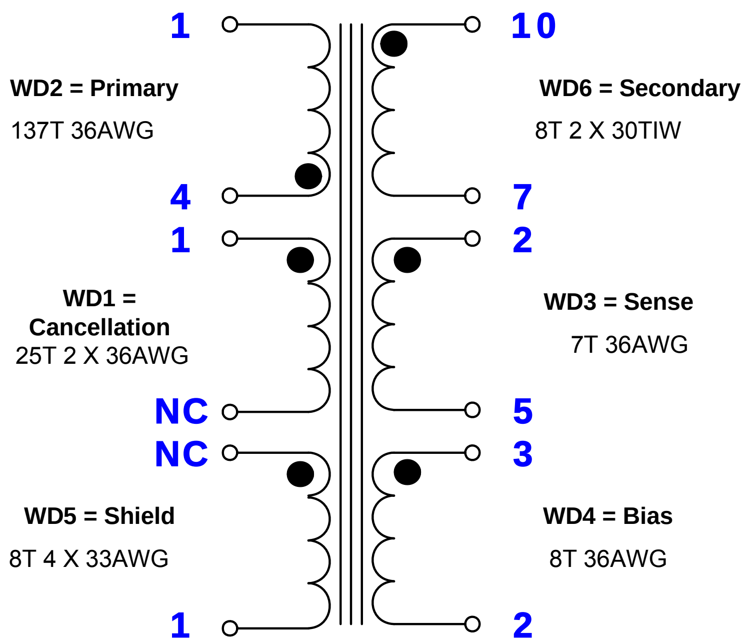


Figure 4 – Transformer Electrical Diagram.

Note: Windings WD3 and WD4 are wound to spread across the entire winding window. These windings interleave each other and there is no tape between these windings.

7.2 Electrical Specifications

Electrical Strength	1 second, 60 Hz, from pins 1-5 to pin 10	3000 VAC
Primary Inductance	Pins 1 and 4 all other windings open, measured at 100 kHz, 0.4 Vrms	3670 uH, -0%/+10%
Resonant Frequency	Pins 1 and 4, all other windings open	600 kHz min.
Primary Leakage Inductance	Pins 1 and 4 with pins 7 and 10 shorted, measured at 100 kHz, 0.4 Vrms	110 uH max.

7.3 Materials

Item	Description
[1]	Core: EE16, NC-2H or equivalent, gapped for ALG = 196 nH/T^2
[2]	Bobbin: EE16, Horizontal, 10 pins (5/5)
[3]	Magnet Wire: #36 AWG
[4]	Magnet Wire: #33 AWG
[5]	Triple Insulated Wire: #30 AWG
[6]	Tape: 3M 1298 Polyester film, 2.0 mils thick, 8.0mm wide
[7]	Varnish

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

7.4 Transformer Build Diagram

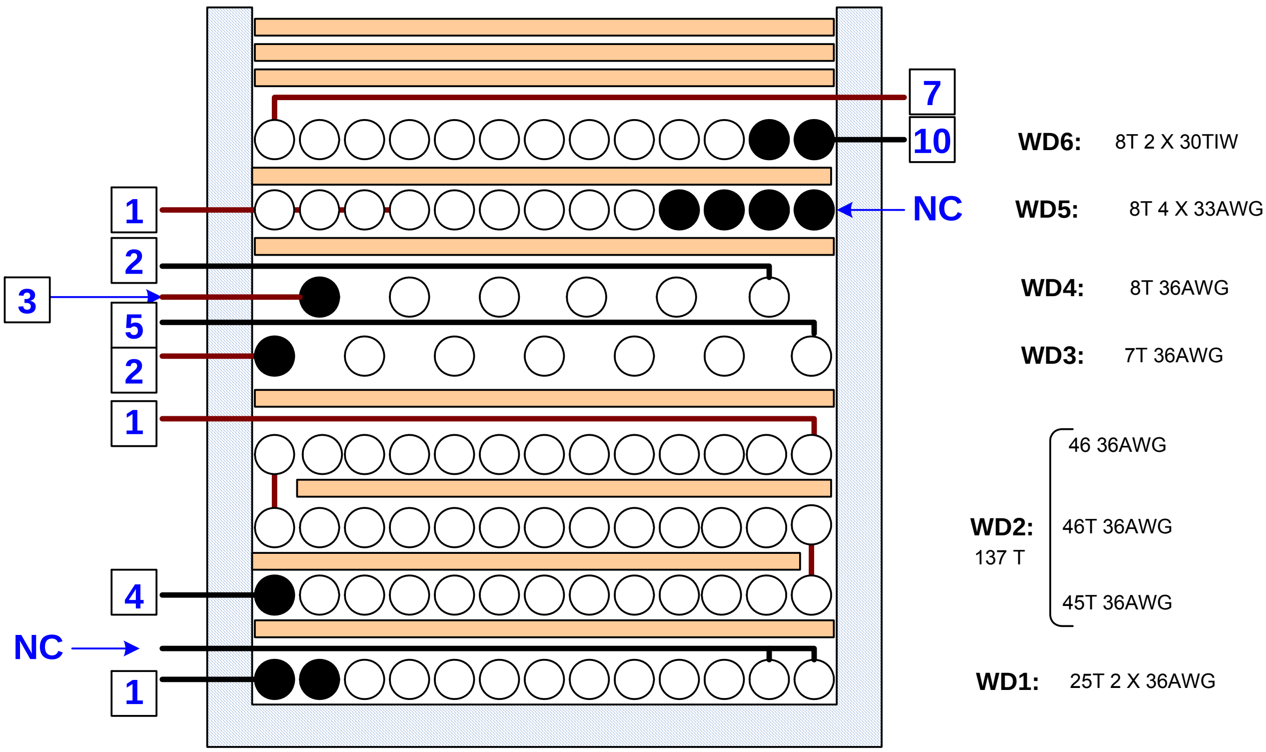


Figure 5 – Transformer Build Diagram.

7.5 Transformer Construction

Core Cancelation	Start at Pin 1. Wind 25 bifilar turns of item [3] in 1 full layer. Cut finish. Apply one layer of tape [6].
Primary	Start at Pin 4. Wind 45 turns of item [3] in approximately 1 layer. Apply one layer of tape [6]. Wind 46 turns on next layer. Apply 1 layer of tape [6]. Wind 46 turns and finish on pin 1.
Basic Insulation	Use one layer of item [6] for basic insulation.
Sense Winding	Starting at Pin 2, wind 7 turns of item [3]. Spread turns evenly across bobbin. Finish at Pin 5.
Bias winding	Start at Pin 3, wind 8 turns of item [3]. Spread turns evenly across bobbin interleaving with Sense winding. Terminate on pin 2.
Basic Insulation	Use one layer of item [6] for basic insulation.
Shield Winding	Temporally start at pin 6. Wind 8 quadfilar turns of item [4] across entire width of bobbin. Terminate on pin 1. Remove start from pin 6 and cut wire such that it fills bobbin width (no gaps).
Basic Insulation	Use one layer of item [6] for basic insulation.
Secondary Winding	Start at Pin 10. Wind 8 bifilar turns of item [5] to fill bobbin layer. Finish on pin 7.
Outer Wrap	Wrap windings with 3 layers of tape item [6].
Final Assembly	Assemble and secure gapped core halves. Varnish impregnate with item [7].

8 Transformer Spreadsheets

ACDC_LNK63X_022509; Rev.1.0; Copyright Power Integrations 2009	INPUT	INFO	OUTPUT	UNIT	ACDC_LNK63X_022509_Rev1-0.xls; Continuous/Discontinuous Flyback Transformer Design Spreadsheet
ENTER APPLICATION VARIABLES					
VACMIN	85			Volts	Minimum AC Input Voltage
VACMAX	265			Volts	Maximum AC Input Voltage
fL	50			Hertz	AC Mains Frequency
VO	5.10			Volts	Output Voltage
PO	2.95			Watts	Output Power
n	0.75				Efficiency Estimate
Z			0.5		Loss Allocation Factor
tC			3	ms	Bridge Rectifier Conduction Time Estimate
Clampless Design	YES				Choose 'YES' from the 'clampless Design' drop down box at the top of this spreadsheet for a clampless design. Choose 'NO' to add an external clamp circuit. Clampless design lowers the total cost of the power supply
CIN	9.40			uFarads	Input Filter Capacitor
ENTER LinkSwitch-II (LNK63X) VARIABLES					
LinkSwitch-II Device	**LNK632DG**		**LNK632DG**		LinkSwitch-II (LNK63X) device
ILIMITMIN			0.135	Amps	LinkSwitch-II (LNK63X) Minimum Current Limit
ILIMITMAX			0.155	Amps	LinkSwitch-II (LNK63X) Maximum Current Limit
fS			100000	Hertz	LinkSwitch-II (LNK63X) Switching Frequency
I2FMIN			1987	A^2Hz	LinkSwitch-II (LNK63X) Min I2F (Power Coefficient)
I2FMAX			2582	A^2Hz	LinkSwitch-II (LNK63X) Max I2F (Power Coefficient)
VOR	96.00		96	Volts	Reflected Output Voltage
VDS			10	Volts	LinkSwitch-II (LNK63X) on-state Drain to Source Voltage
VD			0.5	Volts	Output Winding Diode Forward Voltage Drop
DCON			5.16	us	Output Diode conduction time
KP_TRANSIENT			0.79		Worst case ripple to peak current ratio. Maintain KP_TRANSIENT above 0.25
ENTER TRANSFORMER CORE/CONSTRUCTION VARIABLES					
Core Type	**EE16**		**EE16**		Transformer Core size
Core		*EE16*		*P/N:*	PC40EE16-Z
Bobbin		*EE16_BOBBIN*		*P/N:*	BE-16-118CPH
AE			0.192	cm^2	Core Effective Cross Sectional Area
LE			3.5	cm	Core Effective Path Length
AL			1140	nH/T^2	Ungapped Core Effective Inductance
BW			8.5	mm	Bobbin Physical Winding Width
M			0.00	mm	Safety Margin Width (Half the Primary to Secondary Creepage Distance)
L	3.00		3		Number of Primary Layers
NS			8		Number of Secondary Turns
DC INPUT VOLTAGE PARAMETERS					
VMIN			93	Volts	Minimum DC Input Voltage
VMAX			375	Volts	Maximum DC Input Voltage
FEEDBACK VARIABLES					
NFB			7.00		Feedback winding number of turns
VFLY			4.90	Volts	Voltage on the Feedback winding when LinkSwitch-II (LNK63X) turns off
RUPPER			9.53	k-ohms	Upper resistor of feedback network
RLOWER			6.81	k-ohms	Lower resistor of feedback network
Fine Tuning Section					
Measured Output Voltage	5.40		5.40	k-ohms	Actual (Measured) Voltage at the output of power

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

					supply
RLOWER_FINE			6.19	k-ohms	Adjusted (Fine tuned) value of lower resistor (RLOWER). Do not change value of RUPPER
Bias Winding Parameters					
Add Bias winding			YES		External Bias winding needed. AC stack bias winding on top of Feedback winding
VB	10.50		11	Volts	Bias Winding Voltage
NB			8		Number of Bias winding turns. Bias winding is assumed to be AC stacked on top of the Feedback winding
CURRENT WAVEFORM SHAPE PARAMETERS					
DMAX			0.54		Maximum Duty Cycle
IAVG			0.04	Amps	Average Primary Current
IP			0.14	Amps	Minimum Peak Primary Current
IR			0.11	Amps	Primary Ripple Current
IRMS			0.06	Amps	Primary RMS Current
TRANSFORMER PRIMARY DESIGN PARAMETERS					
LPMIN			3669	uHenries	Minimum Primary Inductance
LP_TYP			4036	uHenries	Typical (Nominal) Primary Inductance
LP_TOL			10		Tolerance of Primary inductance
NP			137		Primary Winding Number of Turns
ALG			215	nH/T^2	Gapped Core Effective Inductance
BM			2223	Gauss	Maximum Flux Density, (BM<2500) Calculated at typical current limit and typical primary inductance
BP			2592	Gauss	Peak Flux Density, (BP<3100) Calculated at maximum current limit and maximum primary inductance
BAC			803	Gauss	AC Flux Density for Core Loss Curves (0.5 X Peak to Peak)
ur			1654		Relative Permeability of Ungapped Core
LG			0.10	mm	Gap Length (Lg > 0.1 mm)
BWE			25.5	mm	Effective Bobbin Width
OD			0.19	mm	Maximum Primary Wire Diameter including insulation
INS			0.04	mm	Estimated Total Insulation Thickness (= 2 * film thickness)
DIA			0.15	mm	Bare conductor diameter
AWG			35	AWG	Primary Wire Gauge (Rounded to next smaller standard AWG value)
CM			32	Cmils	Bare conductor effective area in circular mils
CMA		*Info*	512	Cmils/Amp	CAN DECREASE CMA < 500 (decrease L(primary layers),increase NS,smaller Core)
TRANSFORMER SECONDARY DESIGN PARAMETERS					
Lumped parameters					
ISP			2.31	Amps	Peak Secondary Current
ISRMS			1.00	Amps	Secondary RMS Current
IO			0.58	Amps	Power Supply Output Current
IRIPPLE			0.81	Amps	Output Capacitor RMS Ripple Current
CMS			199	Cmils	Secondary Bare Conductor minimum circular mils
AWGS			27	AWG	Secondary Wire Gauge (Rounded up to next larger standard AWG value)
DIAS			0.36	mm	Secondary Minimum Bare Conductor Diameter
ODS			1.06	mm	Secondary Maximum Outside Diameter for Triple Insulated Wire
INSS			0.35	mm	Maximum Secondary Insulation Wall Thickness
VOLTAGE STRESS PARAMETERS					
VDRAIN			-	Volts	Peak Drain Voltage is highly dependent on Transformer capacitance and leakage inductance. Please verify this on the bench and ensure that it is below 650 V to allow 50 V margin for transformer variation.
PIVB			46	Volts	Bias Diode Maximum Peak Inverse Voltage
PIVS			27	Volts	Output Rectifier Maximum Peak Inverse Voltage

TRANSFORMER SECONDARY DESIGN PARAMETERS (MULTIPLE OUTPUTS)					
1st output					
VO1			5.1	Volts	Output Voltage (if unused, defaults to single output design)
IO1			0.578	Amps	Output DC Current
PO1			2.95	Watts	Output Power
VD1			0.5	Volts	Output Diode Forward Voltage Drop
NS1			8.00		Output Winding Number of Turns
ISRMS1			1.00	Amps	Output Winding RMS Current
IRIPPLE1			0.81	Amps	Output Capacitor RMS Ripple Current
PIVS1			27	Volts	Output Rectifier Maximum Peak Inverse Voltage
CMS1			199	Cmils	Output Winding Bare Conductor minimum circular mils
AWGS1			27	AWG	Wire Gauge (Rounded up to next larger standard AWG value)
DIAS1			0.36	mm	Minimum Bare Conductor Diameter
ODS1			1.06	mm	Maximum Outside Diameter for Triple Insulated Wire
2nd output					
VO2				Volts	Output Voltage
IO2				Amps	Output DC Current
PO2			0.00	Watts	Output Power
VD2			0.7	Volts	Output Diode Forward Voltage Drop
NS2			1.00		Output Winding Number of Turns
ISRMS2			0.00	Amps	Output Winding RMS Current
IRIPPLE2			0.00	Amps	Output Capacitor RMS Ripple Current
PIVS2			3	Volts	Output Rectifier Maximum Peak Inverse Voltage
CMS2			0	Cmils	Output Winding Bare Conductor minimum circular mils
AWGS2			N/A	AWG	Wire Gauge (Rounded up to next larger standard AWG value)
DIAS2			N/A	mm	Minimum Bare Conductor Diameter
ODS2			N/A	mm	Maximum Outside Diameter for Triple Insulated Wire
3rd output					
VO3				Volts	Output Voltage
IO3				Amps	Output DC Current
PO3			0.00	Watts	Output Power
VD3			0.7	Volts	Output Diode Forward Voltage Drop
NS3			1.00		Output Winding Number of Turns
ISRMS3			0.00	Amps	Output Winding RMS Current
IRIPPLE3			0.00	Amps	Output Capacitor RMS Ripple Current
PIVS3			3	Volts	Output Rectifier Maximum Peak Inverse Voltage
CMS3			0	Cmils	Output Winding Bare Conductor minimum circular mils
AWGS3			N/A	AWG	Wire Gauge (Rounded up to next larger standard AWG value)
DIAS3			N/A	mm	Minimum Bare Conductor Diameter
ODS3			N/A	mm	Maximum Outside Diameter for Triple Insulated Wire
Total power			2.95	Watts	Total Output Power
Negative Output			N/A		If negative output exists enter Output number; eg: If VO2 is negative output, enter 2

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

9 Performance Data

All measurements performed at room temperature, 60 Hz input frequency.

9.1 Active Mode Efficiency

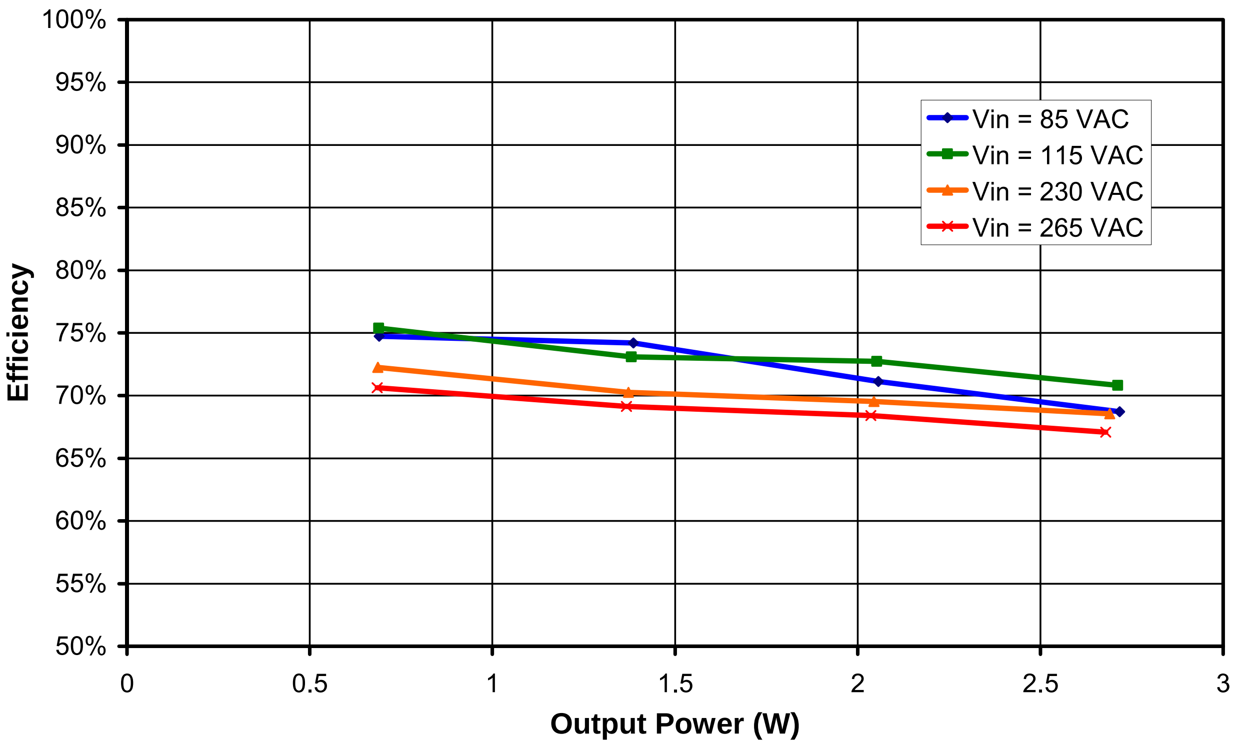


Figure 6 – Efficiency vs. Input Voltage, Room Temperature, 60 Hz.

Percent of Full Load	Efficiency (%)	
	115 VAC	**230 VAC**
25	75.4	72.2
50	73.1	70.3
75	72.7	69.5
100	71.0	68.6
Average	**73.1**	**70.2**
US EISA (2007) requirement	58	
ENERGY STAR 2.0 requirement	*63*	
EC Code of Conduct (v3)	*58*	

Note: Measurements were taken at the end of a 6 foot long #28 AWG 0.6 Ω cable.

9.2 Energy Efficiency Requirements

The external power supply requirements below all require meeting active mode efficiency and no-load input power limits. Minimum active mode efficiency is defined as the average efficiency of 25, 50, 75 and 100% of output current (based on the nameplate output current rating).

For adapters that are single input voltage only then the measurement is made at the rated single nominal input voltage (115 VAC or 230 VAC), for universal input adapters the measurement is made at both nominal input voltages (115 VAC and 230 VAC).

To meet the standard the measured average efficiency (or efficiencies for universal input supplies) must be greater than or equal to the efficiency specified by the standard.

The test method can be found here:

http://www.energystar.gov/ia/partners/prod_development/downloads/power_supplies/EPSupplyEffic_TestMethod_0804.pdf

For the latest up to date information please visit the PI Green Room:

http://www.powerint.com/greenroom/regulations.htm

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

9.2.1 USA Energy Independence and Security Act 2007

This legislation mandates all single output single output adapters, including those provided with products, manufactured on or after July 1st, 2008 must meet minimum active mode efficiency and no load input power limits.

Active Mode Efficiency Standard Models

Nameplate Output (P_O)	Minimum Efficiency in Active Mode of Operation
< 1 W	$0.5 \times P_O$
≥ 1 W to ≤ 51 W	$0.09 \times \ln (P_O) + 0.5$
> 51 W	0.85

ln = natural logarithm

No-load Energy Consumption

Nameplate Output (P_O)	Maximum Power for No-load AC-DC EPS
All	≤ 0.5 W

This requirement supersedes the legislation from individual US States (for example CEC in California).

9.2.2 ENERGY STAR EPS Version 2.0

This specification takes effect on November 1st, 2008.

Active Mode Efficiency Standard Models

Nameplate Output (P_O)	Minimum Efficiency in Active Mode of Operation
≤ 1 W	$0.48 \times P_O + 0.14$
> 1 W to ≤ 49 W	$0.0626 \times \ln(P_O) + 0.622$
> 49 W	0.87

ln = natural logarithm

Active Mode Efficiency Low Voltage Models (V_O<6 V and $I_O \geq$ 550 mA)

Nameplate Output (P_O)	Minimum Efficiency in Active Mode of Operation
≤ 1 W	$0.497 \times P_O + 0.067$
> 1 W to ≤ 49 W	$0.075 \times \ln(P_O) + 0.561$
> 49 W	0.86

ln = natural logarithm

No-load Energy Consumption (both models)

Nameplate Output (P_O)	Maximum Power for No-load AC-DC EPS
0 to < 50 W	≤ 0.3 W
≥ 50 W to ≤ 250 W	≤ 0.5 W

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

9.2.3 EC Code of Conduct Version 3

Active Mode Efficiency Standard Models

Nameplate Output (P_O)	Minimum Efficiency in Active Mode of Operation
≤ 1 W	$0.44 \times P_O + 0.145$
> 1 W to ≤ 36 W	$0.08 \times \ln(P_O) + 0.585$
> 36 W	0.87

ln = natural logarithm

Mobile handheld battery applications

Nameplate Output (P_O)	Minimum Efficiency in Active Mode of Operation
≤ 1 W	$0.5 \times P_O + 0.029$
> 1 W to ≤ 8 W	$0.095 \times \ln(P_O) + 0.529$

ln = natural logarithm

No-load Energy Consumption

Nameplate Output (P_O)	Maximum Power for No-load AC-DC EPS
≥ 0.3 W to < 50 W	≤ 0.25 W
≥ 50 W to < 250 W	≤ 0.5 W

No-load Energy Consumption (mobile handheld battery applications)

Nameplate Output (P_O)	Maximum Power for No-load AC-DC EPS
≥ 0.3 W to ≤ 8 W	≤ 0.25 W (current)
≥ 0.3 W to ≤ 8 W	≤ 0.15 W (from 1/1/2011)

9.3 No-load Input Power

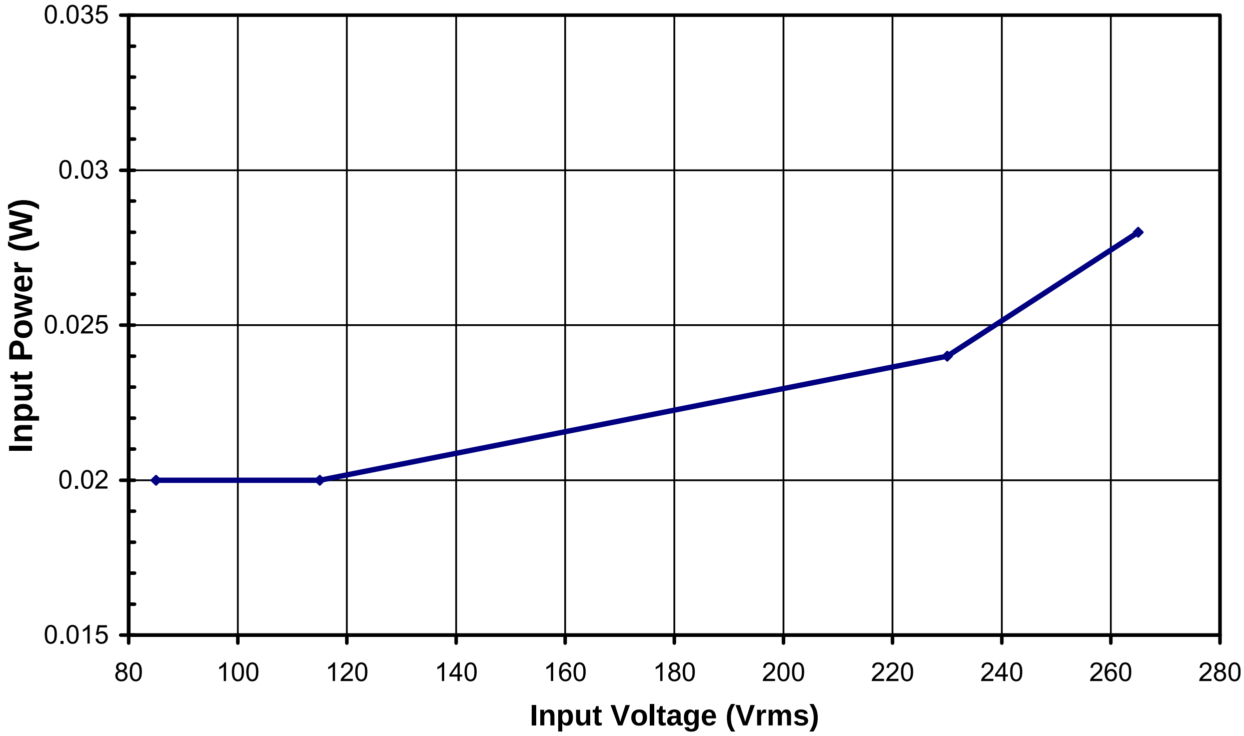


Figure 7 – Zero Load Input Power vs. Input Line Voltage, Room Temperature, 60 Hz.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

9.4 Regulation

9.4.1 Line and Load

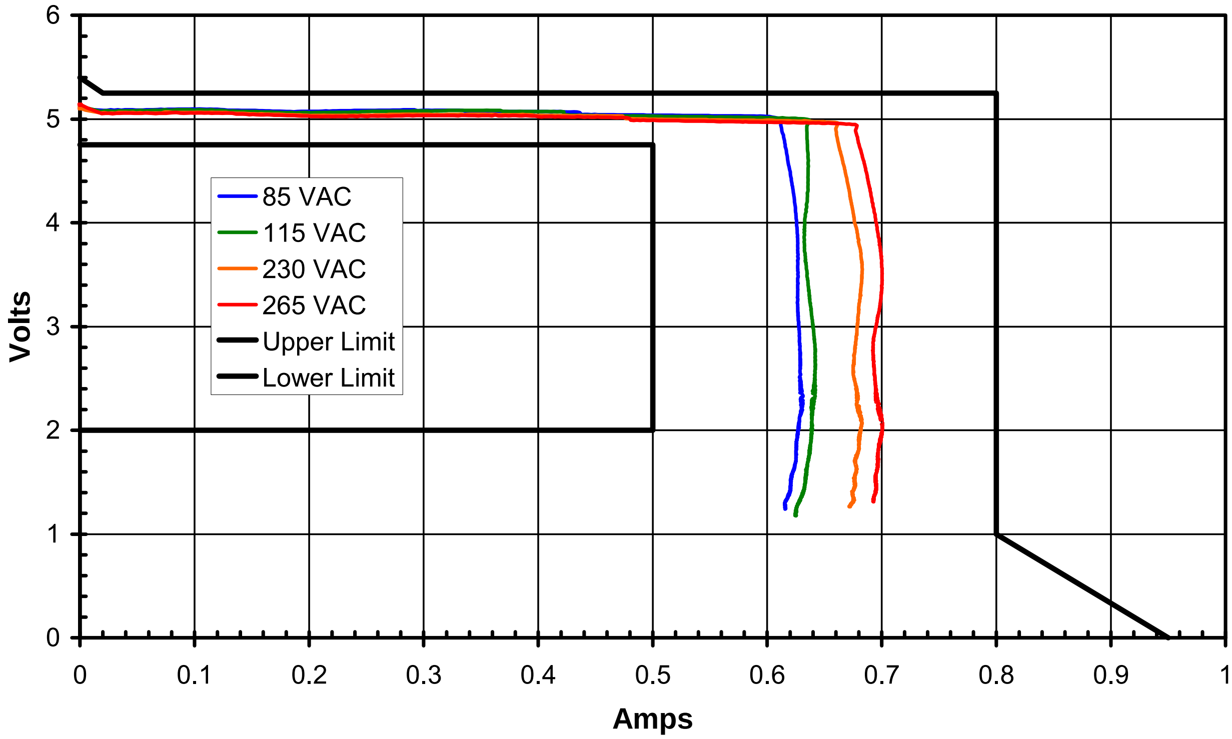


Figure 8 – Line and Load Regulation with 10 μF Bypass Capacitor and 28 AWG Output Cable, Room Temperature.

10 Thermal Performance

The temperature of the LNK632 was measured by soldering a thermocouple to the source pin of the device.

Item	Temperature (°C)			
	85 VAC	115 VAC	230 VAC	265 VAC
Ambient	40	40	40	40
LNK632 (U1)	87	80	83	89

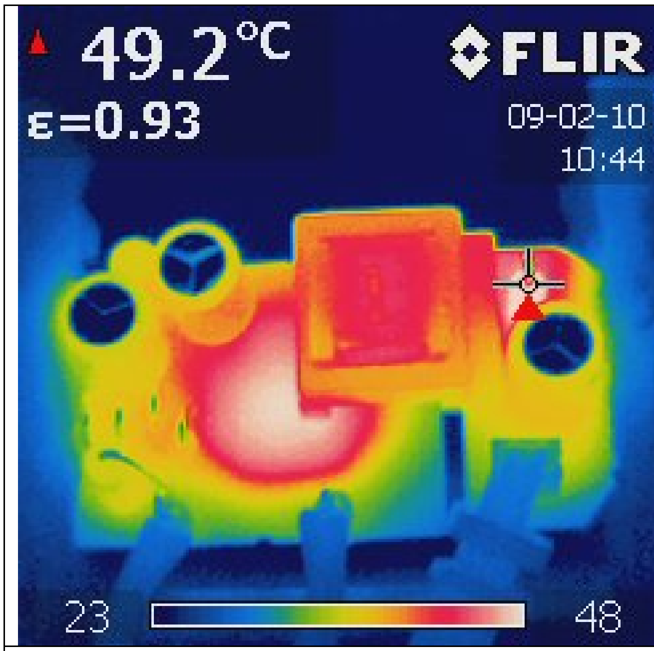


Figure 9 – Thermal Image of Assembly (Top)
$V_{IN:}$ 85 VAC, Full load, Output Rectifier is Highest Recorded Temperature at 49.2 °C.

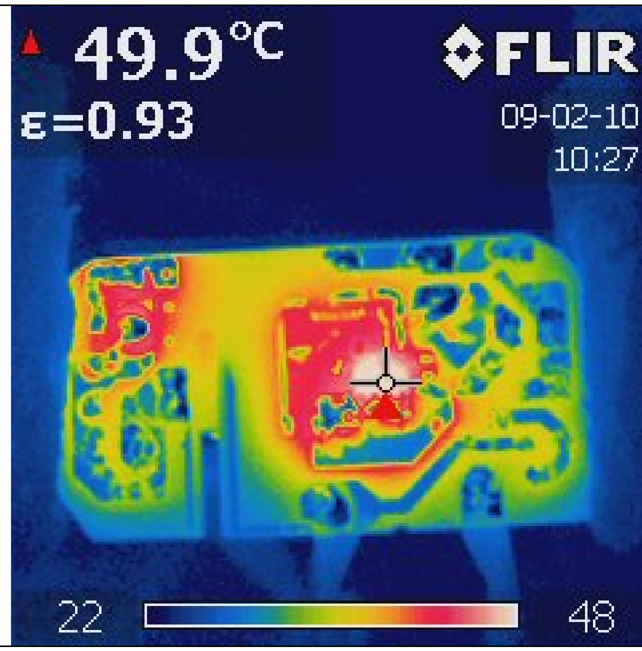


Figure 10 – Thermal Image of Assembly (Bottom)
V_{IN}: 85 VAC, Full Load, LNK632DG is Highest Recorded Temperature at 49.9 deg °C.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

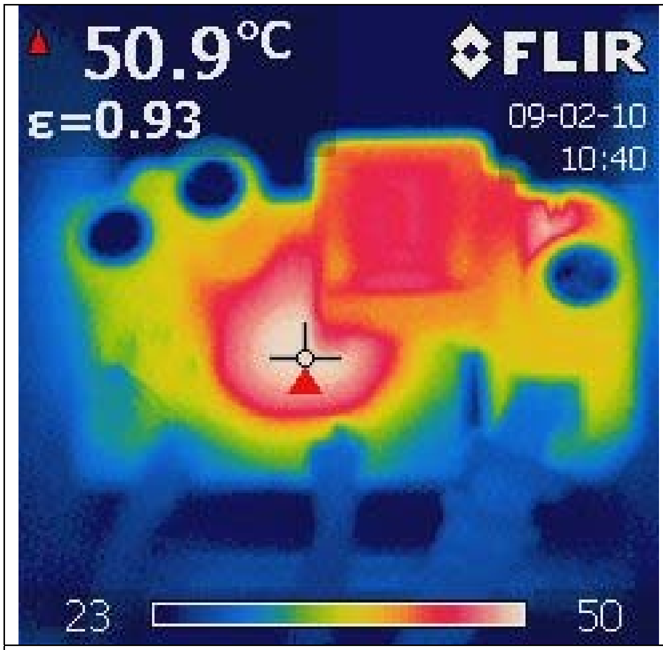
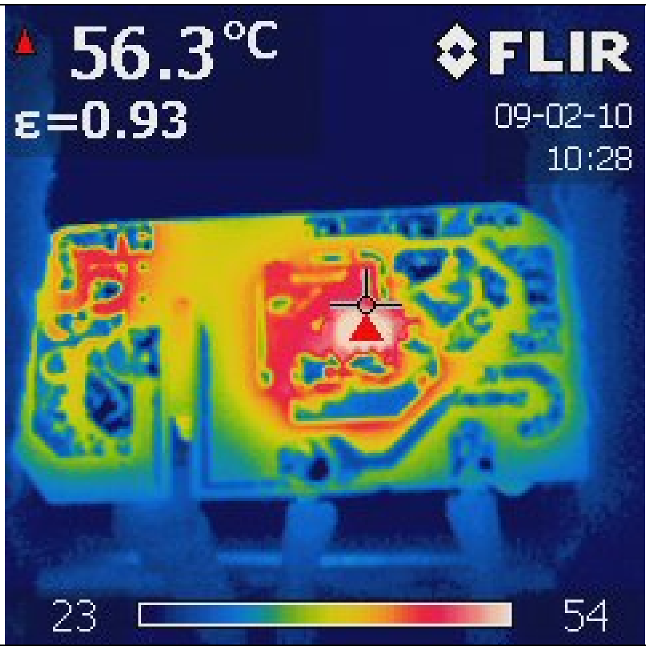
	

Figure 11 – Thermal Image of Assembly (Top) Vin: 265 VAC, Full Load, PCB Heat Sink Area of LNK632DG was Highest Temperature at 50.9 °C.	**Figure 12 –** Thermal Image of Assembly (Bottom) Vin: 265 VAC, Full Load, LNK632DG was Highest Temperature at 56.3 °C.

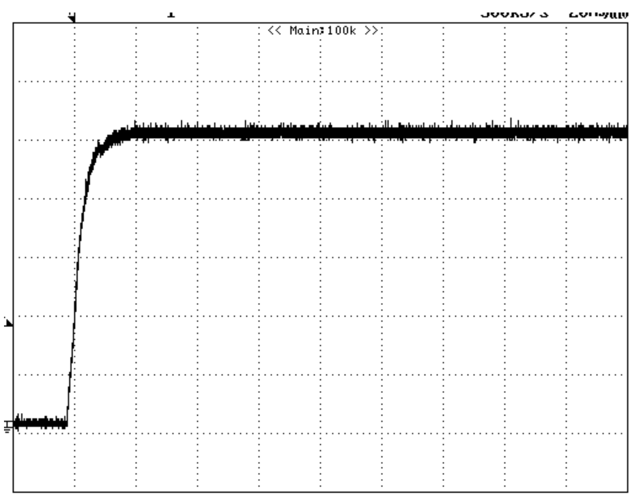
11 Waveforms

11.1 Drain Voltage and Current, Normal Operation

Figure 13 – 85 VAC, Full Load.
Upper: V_{DRAIN}, 200 V / div.
Lower: I_{DRAIN}, 50 mA / div, 2 μs / div.

Figure 14 – 265 VAC, Full Load.
Upper: V_{DRAIN}, 200 V / div.
Lower: I_{DRAIN}, 50 mA / div, 2 μs / div.

11.2 Output Voltage Start-up Profile



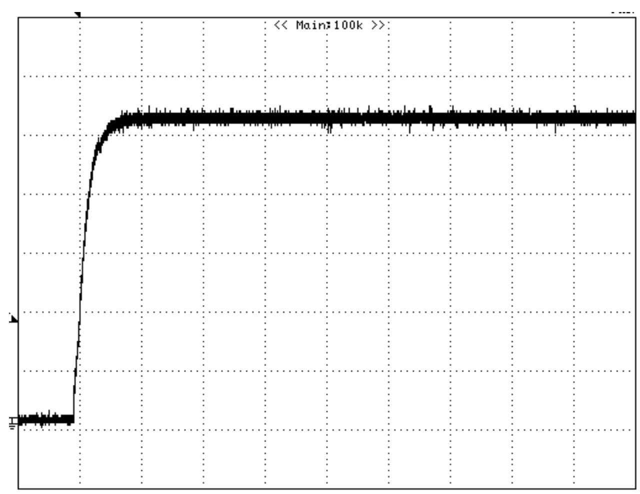


Figure 15 – Start-up Profile, 115 VAC
2 V, 20 ms / div.

Figure 16 – Start-up Profile, 230 VAC
2 V, 20 ms / div.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

11.3 Drain Voltage and Current Start-up Profile

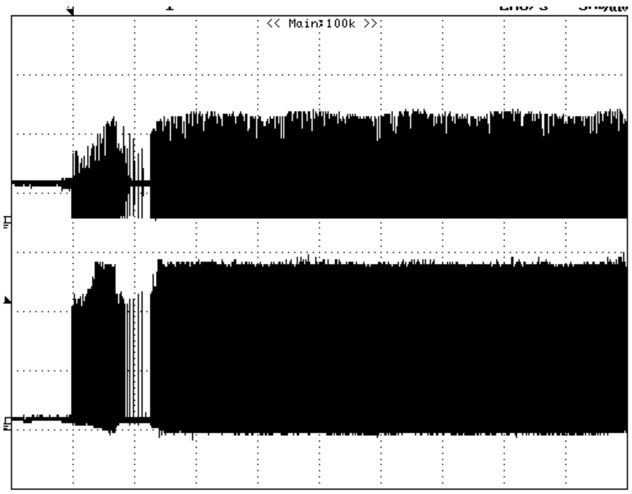


Figure 17 – 85 VAC Input and Maximum Load.
Upper: V_{DRAIN}, 200 V / div.
Lower: I_{DRAIN}, 50 mA / div, 5 ms / div.

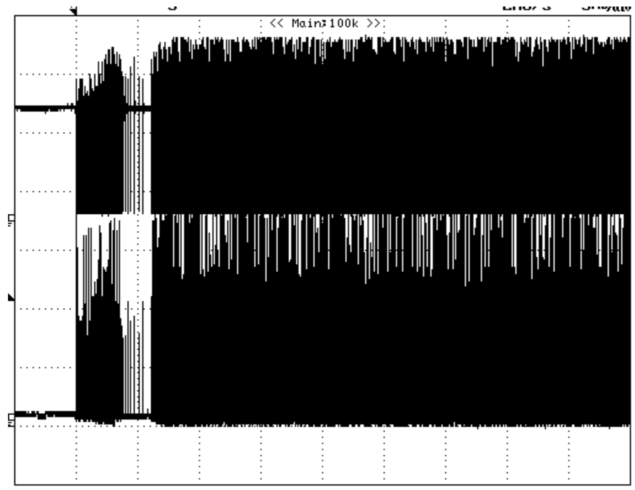


Figure 18 – 265 VAC Input and Maximum Load.
Upper: V_{DRAIN}, 200 V / div.
Lower: I_{DRAIN}, 50 mA / div, 5 ms / div.

11.4 Load Transient Response (75% to 100% Load Step)

In the figures shown below, signal averaging was used to better enable viewing the load transient response. The oscilloscope was triggered using the load current step as a trigger source. Since the output switching and line frequency occur essentially at random with respect to the load transient, contributions to the output ripple from these sources will average out, leaving the contribution only from the load step response.

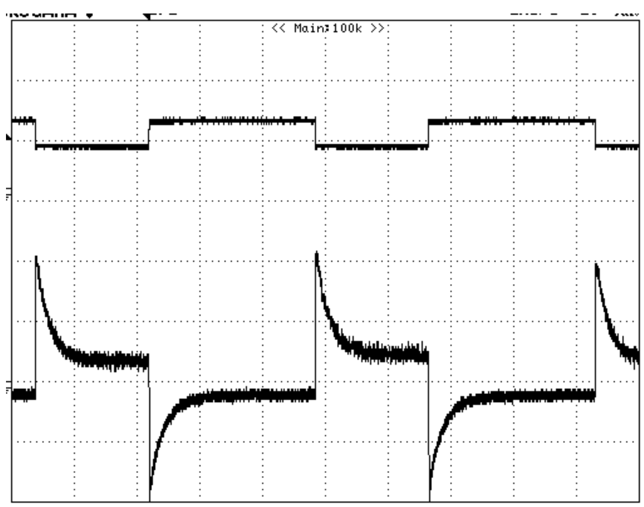


Figure 19 – Transient Response, 115 VAC, 50-100-505% Load Step.
Top: Load Current, 0.5 A/div.
Bottom: Output Voltage
200 mV, 10 ms / div.

Figure 20 – Transient Response, 230 VAC, 50-100-50% Load Step.
Upper: Load Current, 0.5 A/ div.
Bottom: Output Voltage
200 mV, 10 ms / div.

11.5 Short Circuit Output Current

The photos below show the output current during auto-restart with the output shorted at the end of the 28 AWG cable.

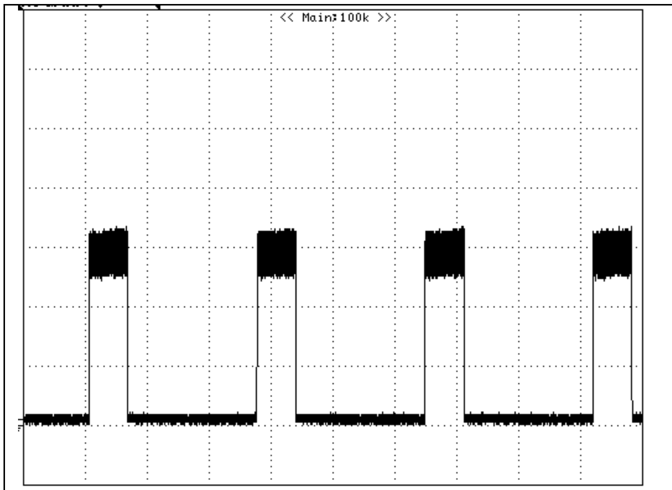


Figure 21 – Short Circuit Output Current, 115 VAC. Output Current 0.2 A/div, 500 ms / div.

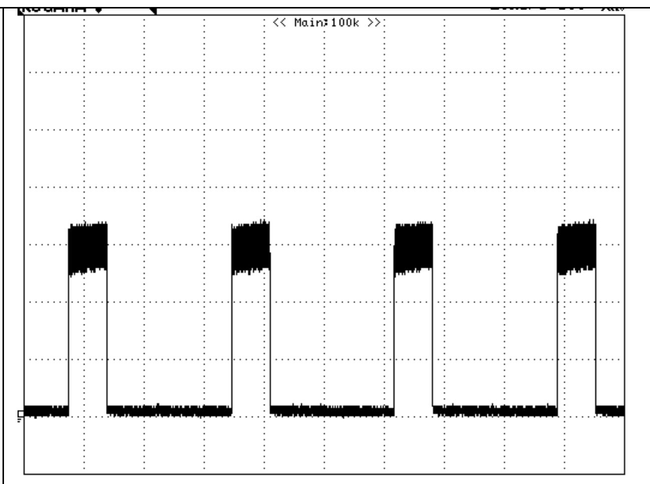


Figure 22 – Short Circuit Output Current, 230 VAC. Output Current 0.2 A/div, 500 ms / div.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

11.6 Output Ripple Measurements

11.6.1 Ripple Measurement Technique

For DC output ripple measurements, a modified oscilloscope test probe must be utilized in order to reduce spurious signals due to pickup. Details of the probe modification are provided below.

The 4987BA probe adapter is affixed with two capacitors tied in parallel across the probe tip. The capacitors include one (1) 0.1 μF/50 V ceramic type and one (1) 1.0 μF/50 V aluminum electrolytic. The aluminum electrolytic type capacitor is polarized, so proper polarity across DC outputs must be maintained (see below).

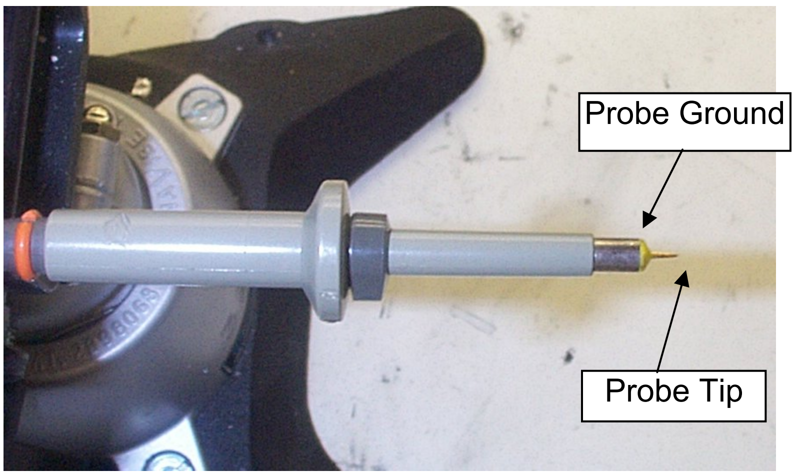


Figure 23 – Oscilloscope Probe Prepared for Ripple Measurement. (End Cap and Ground Lead Removed)

Figure 24 – Oscilloscope Probe with Probe Master (www.probemaster.com) 4987A BNC Adapter. (Modified with wires for ripple measurement, and two parallel decoupling capacitors added)

11.6.2 Measurement Results

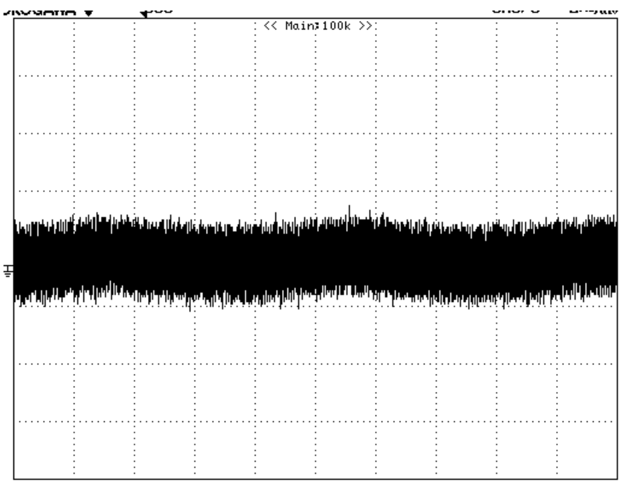


Figure 25 – Ripple, 85 VAC, Full Load.
2 ms, 50 mV / div.

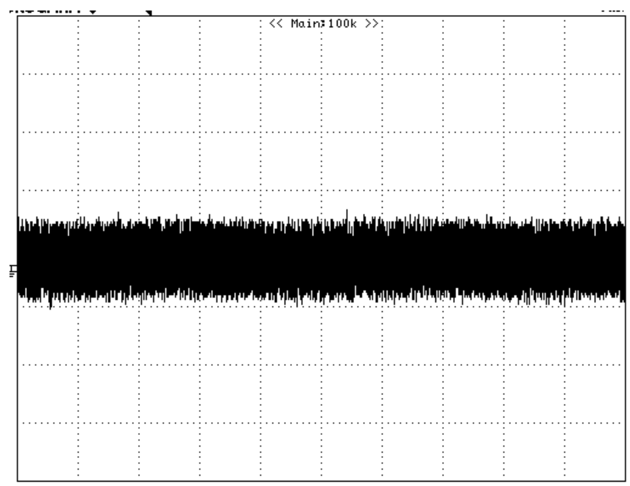


Figure 26 – 5 V Ripple, 115 VAC, Full Load.
2 ms, 50 mV / div.

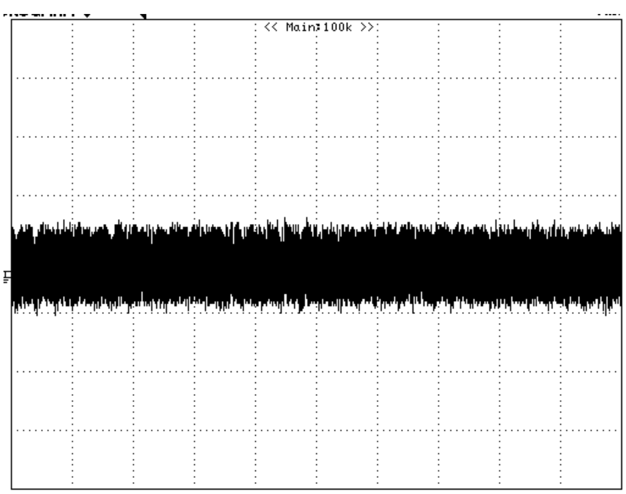


Figure 27 – Ripple, 230 VAC, Full Load.
2 ms, 50 mV /div.

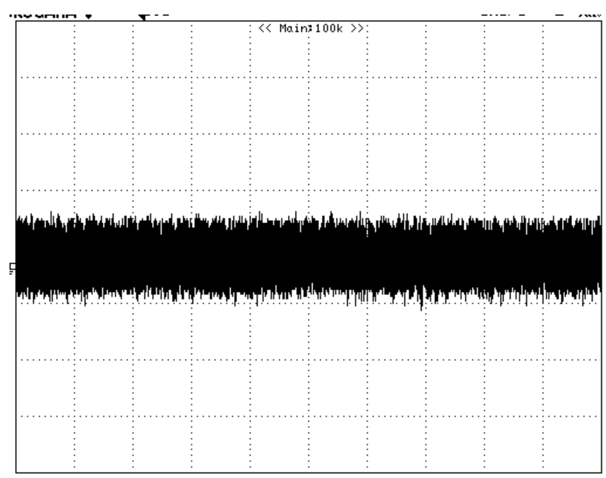


Figure 28 – Ripple, 265 VAC, Full Load.
2 ms, 50 mV /div.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

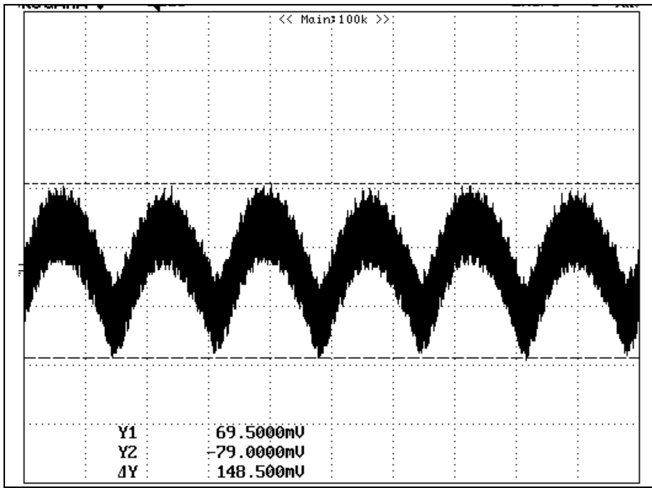


Figure 29 – Worst Case Ripple, 85 VAC, 0.66 A Load (entering CC operation).
Peak to Peak Ripple Voltage = 140 mV
5 ms, 50 mV /div.

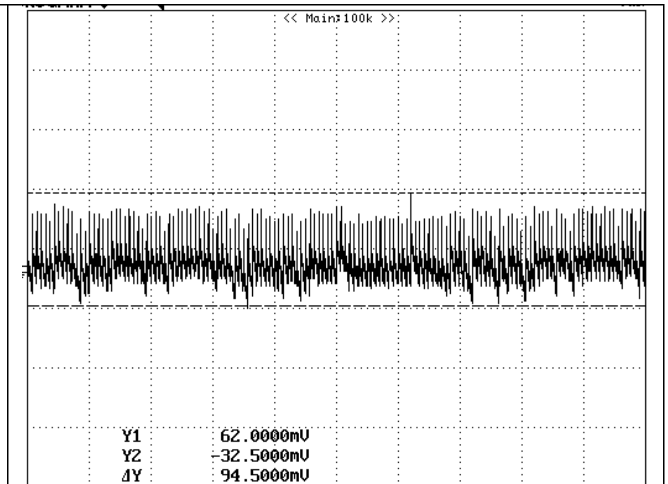


Figure 30 – Worst Case Ripple, 115 VAC, 30 mA Load.
Peak to Peak Ripple Voltage = 94 mV
5 ms, 50 mV /div.

12 Line Surge

Differential and common mode input line 1.2/50 μs surge testing was completed on a single test unit to IEC61000-4-5. Input voltage was set at 230 VAC / 60 Hz. Output was loaded at full load and operation was verified following each surge event.

Surge Level (V)	Input Voltage (VAC)	Injection Location	Injection Phase (°)	Test Result (Pass/Fail)
+1000	230	L to N	90	Pass
-1000	230	L to N	90	Pass
+2000	230	L,N to Output	90	Pass
-2000	230	L,N to Output	90	Pass

100 kHz ring wave, 500 A short circuit current, differential and common mode.

Surge Level (V)	Input Voltage (VAC)	Injection Location	Injection Phase (°)	Test Result (Pass/Fail)
1000	230	L to N	90	Pass
1000	230	L,N to Output	90	Pass

Unit passes under all test conditions.

13 ESD

ESD Level (kV)	Discharge type	Input Voltage (VAC)	Test Result (Pass/Fail)
±15	Air	230	Pass
±15	Contact	230	Pass

Unit passes under all test conditions.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

14 Conducted EMI

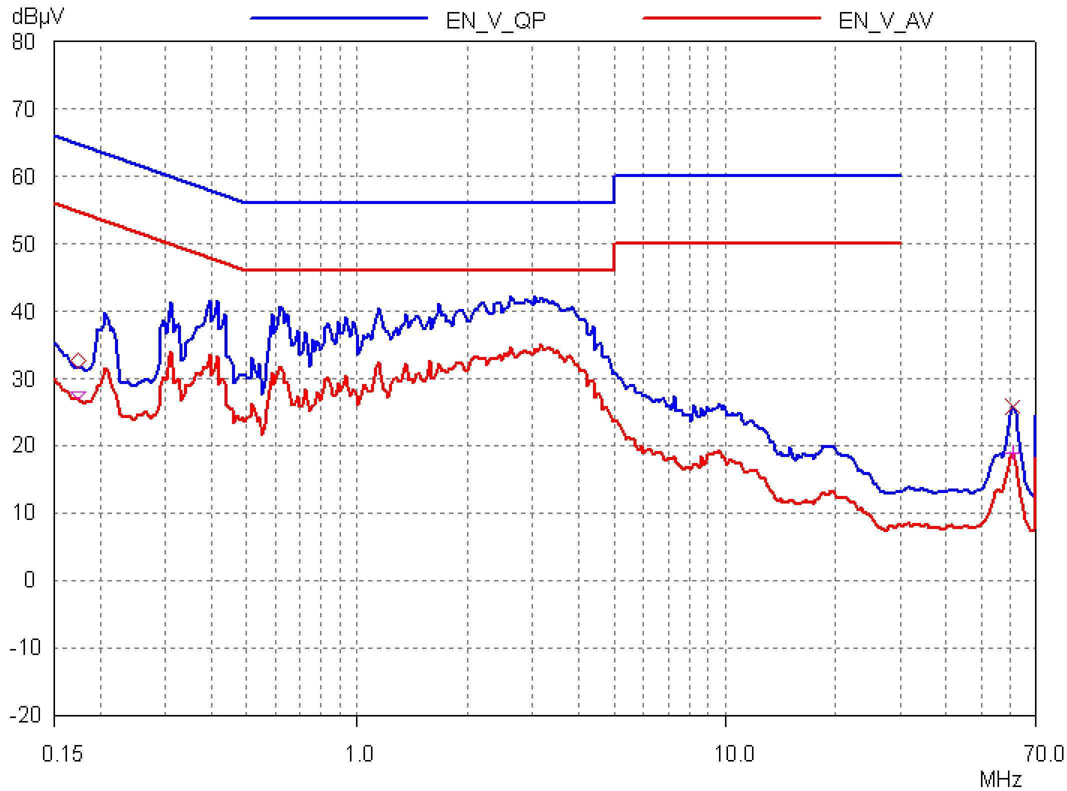


Figure 31 – Conducted EMI, Maximum Steady State Load Without Artificial Hand, 115 VAC, 60 Hz, and EN55022 B Limits.

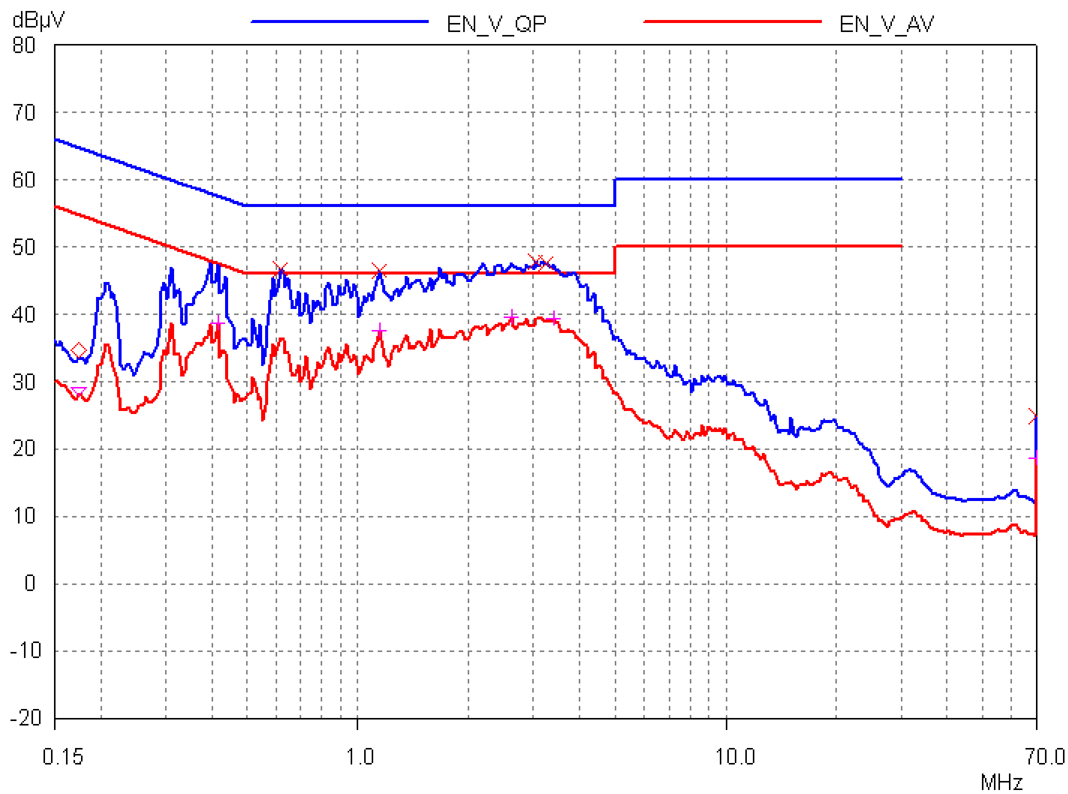


Figure 32 – Conducted EMI, Maximum Steady State Load with Artificial Hand 115 VAC, 60 Hz, and EN55022 B Limits.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

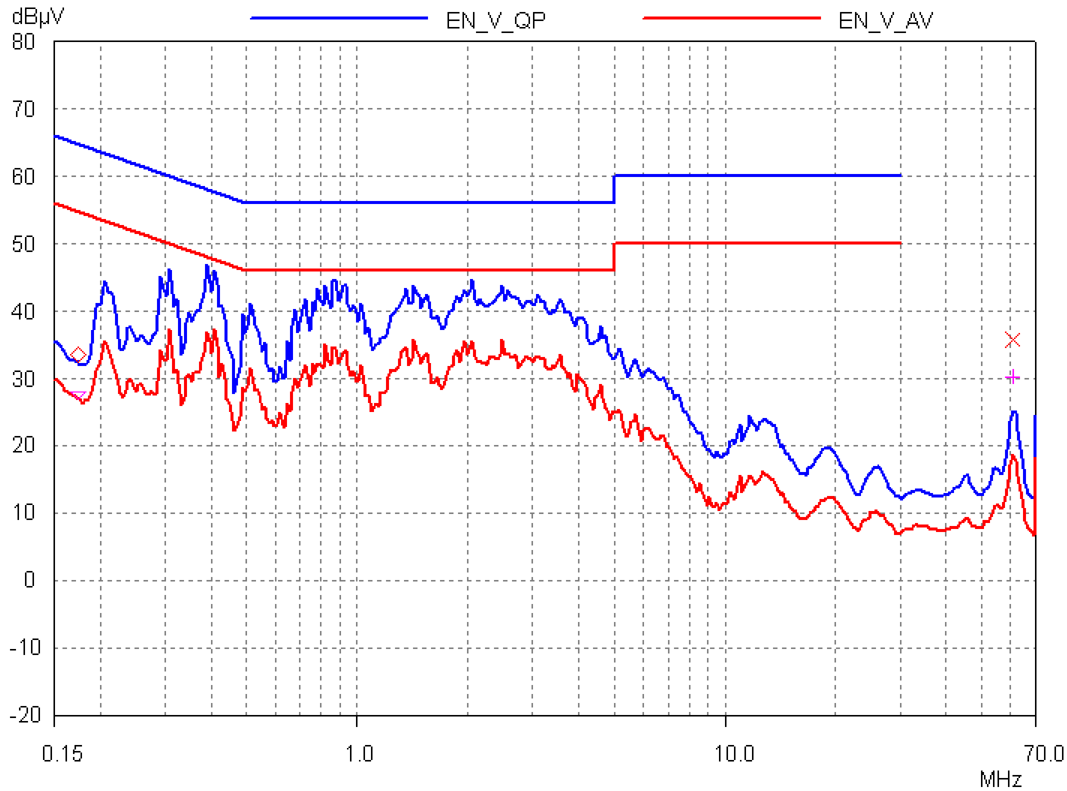


Figure 33 – Conducted EMI, Maximum Steady State Load Without Artificial Hand, 230 VAC, 60 Hz, and EN55022 B Limits.

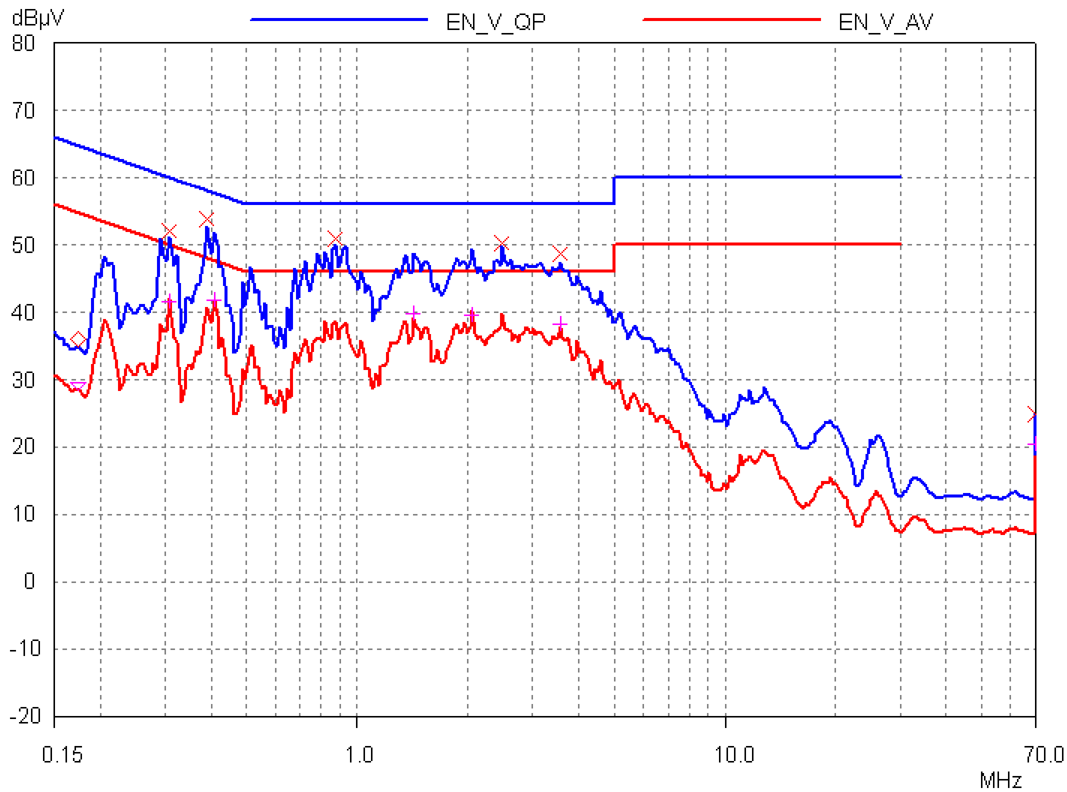


Figure 34 – Conducted EMI, Maximum Steady State Load with Artificial Hand, 230 VAC,60 Hz, and EN55022 B Limits.

Power Integrations
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.powerint.com

15 Revision History

Date	Author	Revision	Description & changes	Reviewed
25-Feb-09	JAC	1.0	Initial Release	PV

For the latest updates, visit our website: www.powerint.com

PATENT INFORMATION

The products and applications illustrated herein (including transformer construction and circuits external to the products) may be covered by one or more U.S. and foreign patents, or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.powerint.com. Power Integrations grants its customers a license under certain patent rights as set forth at http://www.powerint.com/ip.htm.

Power Integrations Worldwide Sales Support Locations

WORLD HEADQUARTERS
5245 Hellyer Avenue
San Jose, CA 95138, USA.
Main: +1-408-414-9200
Customer Service:
Phone: +1-408-414-9665
Fax: +1-408-414-9765
e-mail:
usasales@powerint.com

GERMANY
Rueckertstrasse 3
D-80336, Munich
Germany
Phone: +49-89-5527-3911
Fax: +49-89-5527-3920
e-mail:
eurosales@powerint.com

JAPAN
Kosei Dai-3 Building
2-12-11, Shin-Yokohama,
Kohoku-ku, Yokohama-shi,
Kanagawa 222-0033
Japan
Phone: +81-45-471-1021
Fax: +81-45-471-3717
e-mail: japansales@powerint.com

TAIWAN
5F, No. 318, Nei Hu Rd., Sec. 1
Nei Hu District
Taipei 114, Taiwan R.O.C.
Phone: +886-2-2659-4570
Fax: +886-2-2659-4550
e-mail:
taiwansales@powerint.com

CHINA (SHANGHAI)
Rm 1601/1610, Tower 1
Kerry Everbright City
No. 218 Tianmu Road West
Shanghai, P.R.C. 200070
Phone: +86-021-6354-6323
Fax: +86-021-6354-6325
e-mail:
chinasales@powerint.com

INDIA
#1, 14th Main Road
Vasanthanagar
Bangalore-560052
India
Phone: +91-80-4113-8020
Fax: +91-80-4113-8023
e-mail:
indiasales@powerint.com

KOREA
RM 602, 6FL
Korea City Air Terminal B/D, 159-6
Samsung-Dong, Kangnam-Gu,
Seoul, 135-728
Korea
Phone: +82-2-2016-6610
Fax: +82-2-2016-6630
e-mail: koreasales@powerint.com

UNITED KINGDOM
1st Floor, St. James's House
East Street,
Farnham Surrey, GU9 7TJ
United Kingdom
Phone: +44 (0) 1252-730-141
Fax: +44 (0) 1252-727-689
e-mail:
eurosales@powerint.com

CHINA (SHENZHEN)
Rm A, B & C 4th Floor, Block C,
Electronics Science and
Technology Building
2070 Shennan Zhong Road
Shenzhen, Guangdong,
P.R.C. 518031
Phone: +86-755-8379-3243
Fax: +86-755-8379-5828
e-mail:
chinasales@powerint.com

ITALY
Via De Amicis 2
20091 Bresso MI
Italy
Phone: +39-028-928-6000
Fax: +39-028-928-6009
e-mail:
eurosales@powerint.com

SINGAPORE
51 Newton Road,
#15-08/10 Goldhill Plaza
Singapore, 308900
Phone: +65-6358-2160
Fax: +65-6358-2015
e-mail:
singaporesales@powerint.com

APPLICATIONS HOTLINE
World Wide +1-408-414-9660

APPLICATIONS FAX
World Wide +1-408-414-9760